



Physicochemical Properties of Sodium Bis(2-methylactato)borate Films Doped with Iodine for Photonic Applications

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Abstract

In this work, semiorganic crystal films based on sodium bis(2-methylactato)borate (NaMB) doped with iodine (I_2) were deposited on glass substrates using the dip-coating technique. The chemical, crystalline, and morphological structures were investigated. NaMB semiorganic crystal film has a monoclinic crystal structure with a P21/n space group and a crystallinity degree of 89.8%. Introducing I_2 into NaMB films reduces the crystallinity of the semiorganic crystal films. Moreover, the optical and electrical properties were investigated, including the refractive index, extinction coefficient, band structure, optoelectronic parameters, and electrical conductivity. Adding I_2 to NaMB films led to a decrease in the bandgap energy due to the formation of polarons between the valence and conduction bands. Finally, NaMB/ I_2 semiorganic crystal film conductivity increases as the I_2 concentration increases, creating deep localized states in NaMB, leading to gap-state density changes by shifting the Fermi level and increasing the electrical conductivity.

Keywords Semiorganic crystal films · sodium bis(2-methylactato) borate (NaMB) · iodine (I_2) · electronic transition band · electrical conductivity

Introduction

In recent years, semiorganic crystal films have attracted increasing scientific research attention because of their interesting applications in photonic, optoelectronic, and sensor devices.^{1–4} Semiorganic crystal films were developed due to their excellent optical and electrical properties and reliable physicochemical stability.^{5,6} For instance, these films have high transparency, chemical flexibility, and thermal and mechanical stability.⁷

Research has focused on synthesizing semiorganic crystalline thin films grown using 2-methylactac acid due to

the presence of H-bonding to improve their optoelectronic and physicochemical properties.⁸ Gokila et al.⁸ synthesized bis(2-methylactato)borate tetrahydrate to demonstrate the orthorhombic structure, which revealed fair crystallinity and transmission bandwidth between 220 nm and 1100 nm. Gokila et al.^{9,10} then reported that sodium bis(2-methylactato)borate (NaMB) hemihydrate has good crystallinity and excellent optical properties, making it a potential candidate for many optoelectronic applications due to its high transparency in the visible region.

The physical and chemical properties of complex composites grown based on NaMB hemihydrate doped with iodine (I_2) as novel materials were inspected to develop convenient films for optoelectronic applications. Iodine influences organic–halogen complexes, which affects their optical and dielectric properties.¹¹ The electrical conductivity of the semiorganic crystal films increases by incorporation of electron donors or acceptors.¹² Iodine (I_2) was chosen as the electron acceptor dopant in the polymers because of its significant influence on the optical, electrical, and dielectric properties.^{13,14} Therefore, the physicochemical properties of the NaMB/ I_2 semiorganic crystal films were investigated via their chemical, crystalline, morphological, and thermal properties. In addition, the optical and electrical properties

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of the NaMB/I₂ semiorganic crystal film were explored to investigate their feasibility in optoelectronic and photonic applications.

Experimental Details

Synthesis of Semiorganic Crystal Films Based on NaMB/I₂

NaMB thin films were fabricated by dissolving 4.164 g of 2-methylactic acid (C₄H₈O₃, 104.11 g mol⁻¹, Sigma-Aldrich) in 100 mL deionized water using a magnetic stirrer, after which 1.236 boric acid (H₃BO₃, 61.83 g mol⁻¹, Sigma-Aldrich) was added to the 2-methylactic acid solution. Finally, 1.050 g of sodium carbonate (Na₂CO₃, 105.99 g mol⁻¹, Sigma-Aldrich) was added to the mixed solution. The NaMB solution was homogenized using a magnetic stirrer for 2 h at room temperature. Then, NaMB/I₂ solutions with various weight percentages of I₂ (2.5, 5, 10 wt.%) were prepared by adding iodine (I₂, 253.8089 g mol⁻¹, Sigma-Aldrich) to the NaMB solution under continuous stirring at room temperature for 2 h. In addition, 1.0 g of polyvinylpyrrolidone (PVP) was added to the final solutions before deposition of the films to enhance their adhesion property. NaMB/I₂ films were prepared by immersing the glass substrates in the solutions for 2 h to produce one-layer semiorganic crystal films with 500 nm thickness.

Characterizations of Semiorganic Crystal Films Based on NaMB Doped with I₂

A double-beam UV-Vis spectrophotometer (U-3900H) and four-point probe (Microworld) connected to a high-resolution multimeter (Keithley 2450 SourceMeter) were used to investigate the optical and electrical properties of the films. Fourier transform infrared spectrometry (FTIR) (Bruker Tensor 27 spectrometer) was used to investigate the chemical structural bonding by studying the vibrational bands. Moreover, the structural and morphological properties were investigated using x-ray diffraction analysis (XRD) (Malvern Panalytical Ltd) and scanning electron microscopy (SEM) (FEI Quanta 450 FEG).

Results and Discussion

Chemical Structure Analysis

The asymmetric unit of NaMB [Na(C₈H₁₂BO₆)] is composed of sodium cation and bis(2-methylactato) borate

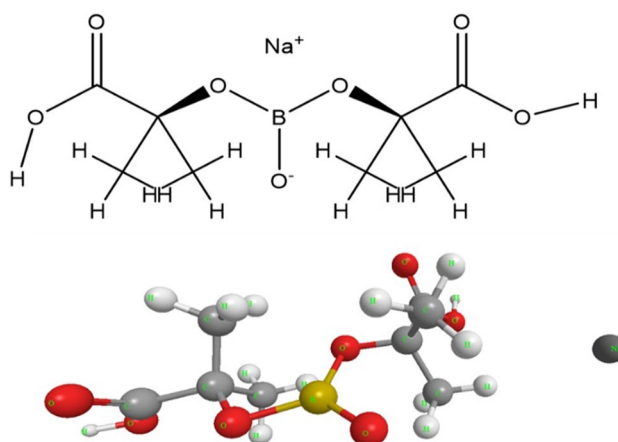


Fig. 1 2D and 3D molecular structure of NaMB crystal (data imported from reference).⁹

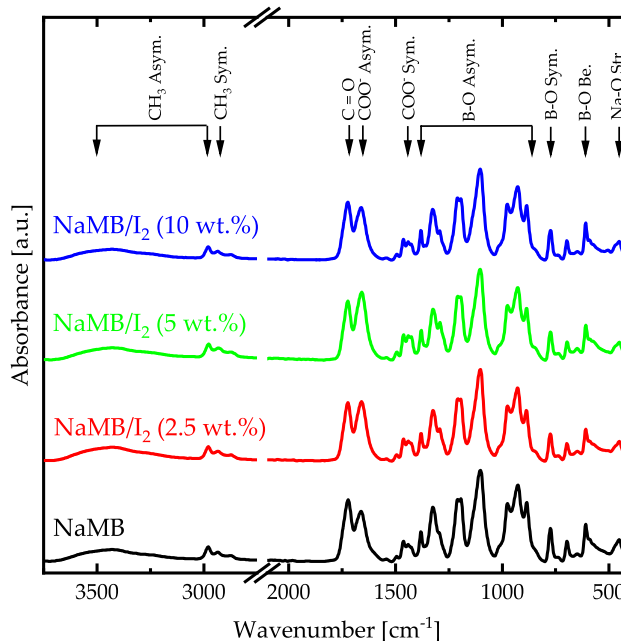


Fig. 2 FTIR spectra of NaMB/I₂ semiorganic crystal films.

anion (Fig. 1). The NaMB film has infrared (IR) bands at 3400 cm⁻¹, 2900 cm⁻¹ (CH₃ asymmetric stretching), 2930 cm⁻¹ (CH₃ symmetric stretching), 1720 cm⁻¹ (C=O stretching), 1655 cm⁻¹ (COO⁻ asymmetric stretching), 1450 cm⁻¹ (COO⁻ symmetric stretching), 1380–880 cm⁻¹ (B-O asymmetric stretching), 775 cm⁻¹ (B-O symmetric stretching), 610 cm⁻¹ (B-O bending), and 460 cm⁻¹ (Na-O stretching) (Fig. 2). Doping of NaMB films with I₂ changes the band line width and positions due to the difference in the electronegativity of iodine and the NaMB atoms.¹⁴

Structural and Morphological Analysis

Structural analysis of the NaMB/I₂ semiorganic crystal film was performed using the powder XRD method (Fig. 3a). The indexing of the XRD peaks was investigated using Qualx2 qualitative phase analysis software. NaMB semiorganic crystal film has a monoclinic structure with a P21/n space group, with different diffraction peaks at Bragg's angles (Miller indices) 11.82° (011), 12.59° (110), 17.49° (002), 18.96° (120), 21.18° (210), 22.51° (121), 23.99° (022), 28.63° (122), 29.93° (300), 31.49° (032), 36.34° (041), and 38.43° (231). The XRD peaks agree well and match the standard monoclinic NaMB (JCPDS 00-155-0583). In addition, X'Pert HighScore Plus software was used to calculate the unit cell parameters (Table I), which also agree with the literature.^{9,10} The degree of crystallinity of the NaMB semiorganic crystal films was evaluated using the equation: $X_{\text{cryst}} = 100\% \times A_{\text{crys}} / (A_{\text{crys}} + A_{\text{Amp}})$ and found to be 89.8%, indicating it has a highly crystal structure. Doping of NaMB with I₂ decreases the film's degree of crystallinity to 74.1% with an iodine weight percent of 10 wt.%. The reduction in the crystallinity orders upon iodine incorporation is attributed to the structural disruption of the NaMB due to its interaction with iodide (I⁻), triiodide (I₃⁻), and the molecular iodine (I₂), which reduces the intermolecular interactions in the NaMB crystals. NaMB semiorganic crystal film demonstrates a crystal nature with a semi-smooth surface (Fig. 3b). Doping of NaMB film with I₂ (10 wt.%)

decreases the crystal nature and increases the film's roughness (Fig. 3c).

Williamson–Hall method (WH) was used to calculate the crystallite size (D) and microstrain (ϵ) based on the following equation¹⁵:

$$\beta_{\text{hkl}} \cos \theta = \frac{k\lambda}{D} + 4\epsilon \sin \theta \quad (1)$$

where β_{hkl} is the diffraction peak line width (in radians), θ is the diffraction angle, and k is the Scherrer constant and is equal to 0.9. A plot of ($4\sin\theta$) versus ($\beta_{\text{hkl}}\cos\theta$) in relevance to each diffraction peak reveals the crystallite size (D) and the microstrain (ϵ) (Table I). The crystallite size is similar to

Table I The crystal and thermal parameters of NaMB/I₂ semiorganic crystal films.

Parameter	NaMB	NaMB/I ₂ (2.5 wt.%)	NaMB/I ₂ (5 wt.%)	NaMB/I ₂ (10 wt.%)
a [Å]	10.0	10.0	10.0	10.0
b [Å]	11.1	11.2	11.2	11.2
c [Å]	11.3	11.4	11.4	11.4
β [°]	116.1	116.1	116.1	116.1
X_{cryst} [%]	89.8	83.3	81.8	74.1
D [nm]	16	16	16	16
$\langle \epsilon \rangle \times 10^{-3}$	2.2	3.1	6.7	9.4
T_m [°C]	71.2	72.6	78.4	82.7
ΔH_m [J/g]	6.39	6.19	3.84	3.52

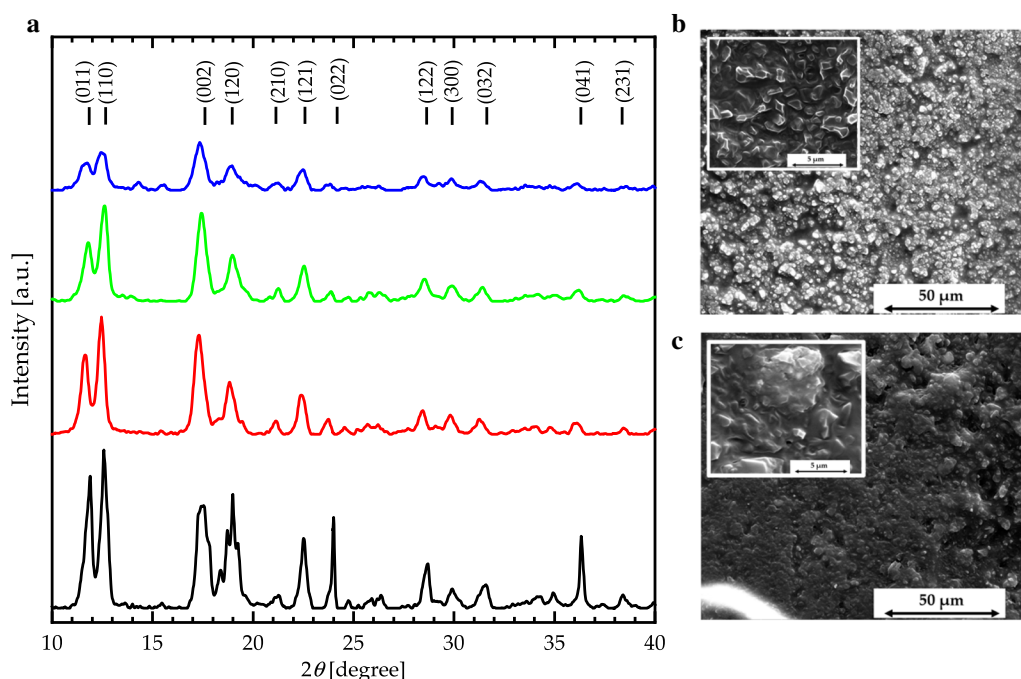


Fig. 3 (a) XRD pattern of NaMB/I₂ semiorganic crystal films, (b) SEM micrograph of NaMB semiorganic crystal films, and (c) SEM micrograph of NaMB/I₂ (10 wt.%) semiorganic crystal films.

all NaMB/I₂ semiorganic crystal films (16 nm). The reason is that iodine interacts with sodium ions outside the host matrix and does not affect the crystallite size of the main composite. However, the microstrain value increases as I₂ concentration increases in the NaMB crystals, which is consistent with the crystallinity degree results.

Differential Scanning Calorimetry (DSC)

Figure 4 shows the DSC curves of NaMB/I₂ semiorganic crystal films with different concentrations of I₂ -revealing endothermic peaks relevant to their melting temperatures (T_m). The DSC curve shows that the melting temperature of the pure NaMB was around 70°C with a melting enthalpy (ΔH_m) of 6.39 J/g (Table I). Increasing I₂ in the NaMB films up to 10 wt.% increases the melting temperature until it reaches 83°C. In addition, the melting enthalpy (ΔH_m) decreases continuously to 3.82 J/g as I₂ concentration increases to 10 wt.%.

Optical Properties and Electronic Band Structure

The transmittance spectrum of NaMB semiorganic crystal film increases abruptly from 0 to 88% as the incident photon wavelength increases from 300 to 380 nm, with variations no longer occurring in the spectral range of 380–700 nm (Fig. 5a). The significant transmittance of the NaMB films is attributed to the lack of free electrons in the NaMB crystals. However, knocking out the crystal electrons in the valance band and transforming them into the conduction band requires high photon energy (UV light). The incorporating of I₂ into the NaMB crystal films leads to shifting of the absorption edge to the red region, consequently decreasing

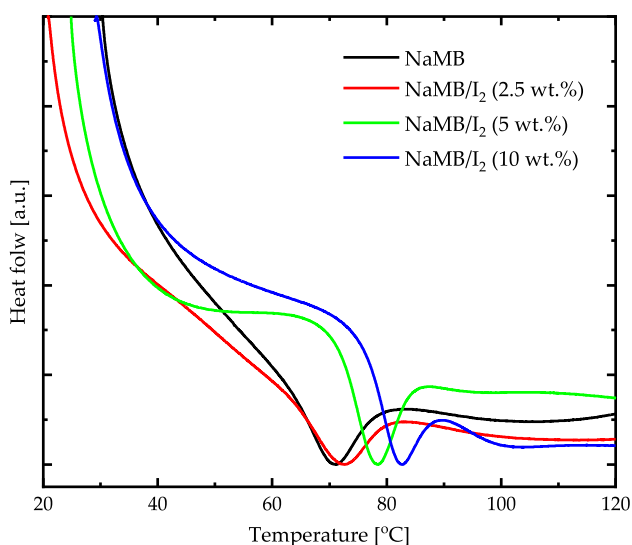


Fig. 4 DSC curves of NaMB/I₂ semiorganic crystal films.

the bandgap energy due to the formation of polaron states between the valance and conduction bands. In addition, NaMB/I₂ semiorganic crystal film (10 wt.%) has lower transmittance than that of the other films due to the free photon-absorbing electrons in iodide (I⁻) and triiodide (I₃⁻) ions with lower energies. NaMB semiorganic crystal films with the incorporation of I₂ have transmittance values of zero in the spectral range of 250–400 nm, which means that NaMB/I₂ semiorganic crystal films could be feasible as UV-light-shielding filters. The reflectance spectra exhibit a decreasing trend, with a broad drop in the spectral range of 300–500 nm (Fig. 5b), resulting from the formation of the polaron states between the valance and conduction bands of the NaMB composite.

The extinction coefficient (k) was calculated by the equation $k = \alpha \lambda / 4\pi$, where α is the absorption coefficient, given by $\alpha = (1/d) \ln((1 - R)/T)$.¹⁶ The k -spectrum for NaMB semiorganic crystal film has an absorption band at 280 nm due to the electron transition band between the valance and conduction bands (Fig. 5c). The low k -values of the NaMB semiorganic crystal film indicate that the photons pass through the film without any scattering or absorption. The k -spectra of the NaMB/I₂ semiorganic crystal films have two additional sub-bands at I₂ concentrations of 2.5 and 5 wt.% and three additional sub-bands at I₂ concentrations of 10 wt.% at 300, 360, and 420 nm, which represents the complex formation between NaMB and I⁻, I₃⁻, and I₂ molecules (Fig. 6).¹⁷ The dissolution of I₂ in the NaMB crystals can be described as¹⁸:



The refractive index (n) spectra were investigated based on the reflectance and extinction coefficient values using the equation $n = (1 + R/1 - R) + \sqrt{(4R/(1 - R)^2) - k^2}$.¹⁶ The n -spectrum of NaMB semiorganic crystal film decreases from 2.1 to 1.5 as the incident photon wavelength increases from 250 nm to 700 nm (Fig. 5d). The reflectance spectra exhibit a decreasing trend, with a vast drop in the spectral range of 300–500 nm, resulting from the formation of polaron states between the valance and conduction bands of NaMB.

The Tauc method was used to determine the optical bandgap energy of the NaMB/I₂ semiorganic crystal films by plotting $(\alpha h\nu)^2$ versus $h\nu$, according to the Tauc equation $(\alpha h\nu)^2 = \beta(h\nu - E_g)$.^{19,20} In addition, the substates between the valance and conduction bands resulting from the disorder in the NaMB/I₂ semiorganic crystal films were investigated using the Urbach energy (E_U) via the equation $\alpha = \alpha_0 \exp(h\nu/E_U)$.²¹ Increasing I₂ in the NaMB crystal decreased the E_g value and increased the E_U

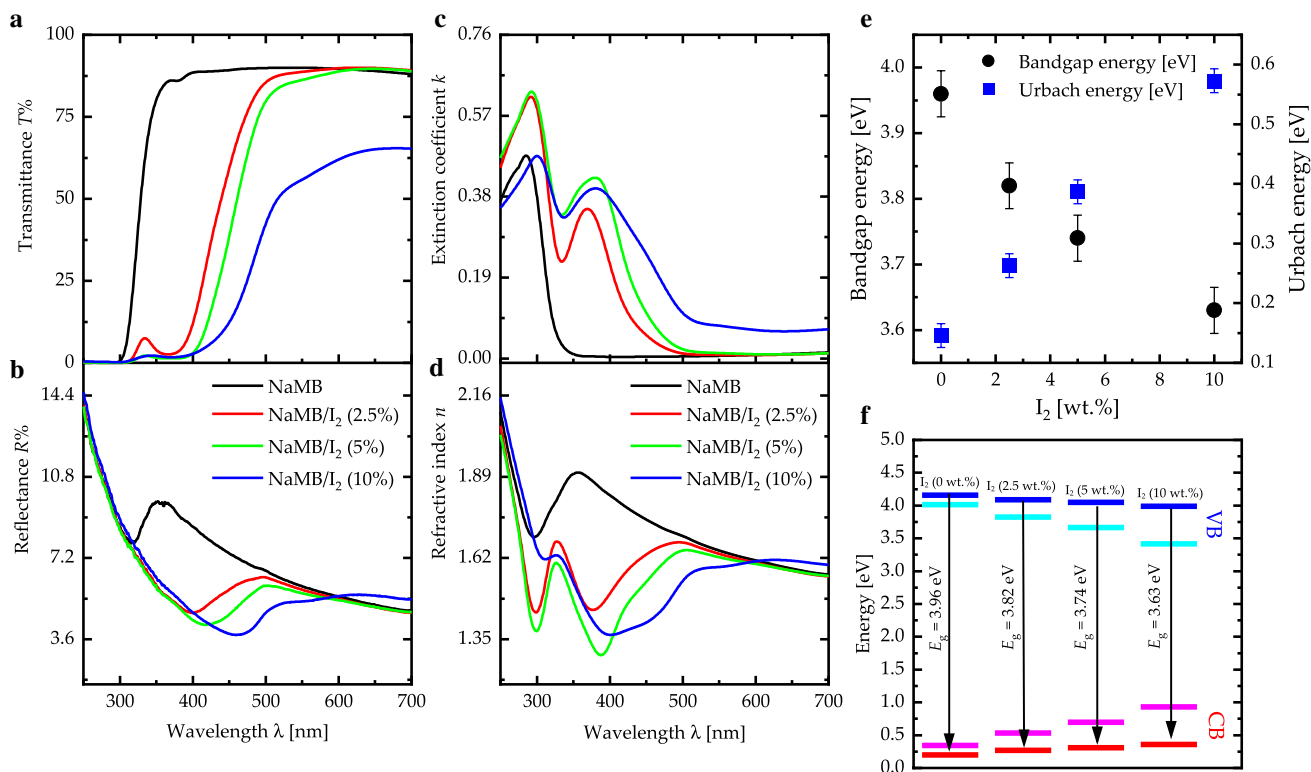


Fig. 5 (a) Transmittance, (b) reflectance, (c) extinction coefficient, (d) refractive index spectra of NaMB/I₂ semiorganic crystal films, (e) optical bandgap energy and Urbach energy of NaMB/I₂ semiorganic

crystal films as a function of I₂ concentration, and (f) schematic diagram of the band structure for NaMB/I₂ semiorganic crystal films.

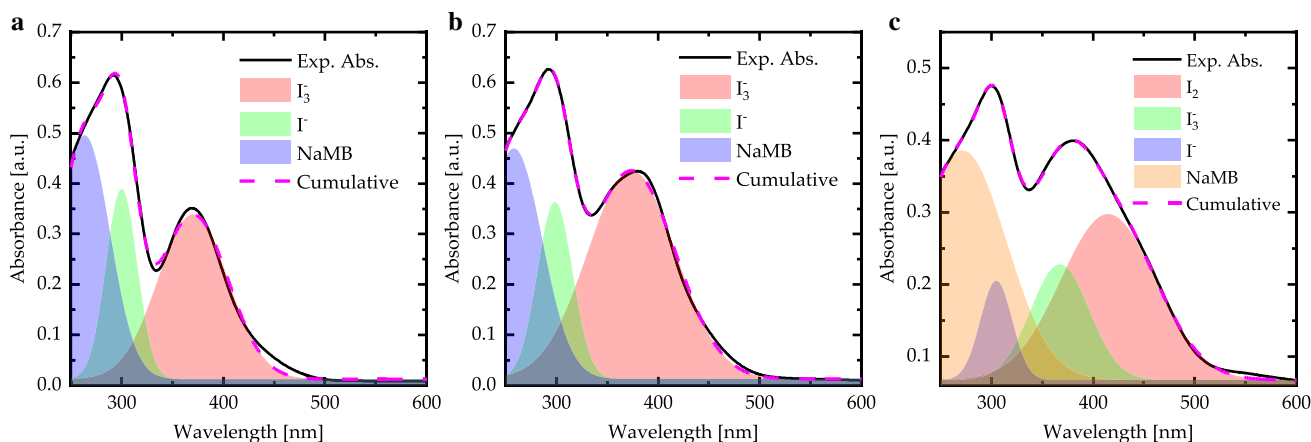


Fig. 6 The multiple peaks fit NaMB/I₂ semiorganic crystal film's extinction coefficient spectra with I₂ concentrations of (a) 2.5 wt.%, (b) 5 wt.%, and (c) 10 wt.%.

value (Fig. 5e), which means that the NaMB exhibited cationic behavior, with the iodine anion forming polaron states between the valence and conduction bands, and consequently decreasing the bandgap energy.²² In addition, the abrupt increase in the bandgap energy of the NaMB/I₂ semiorganic crystal film upon increasing the I₂

concentration changed the film behavior from dielectric to semiconducting. Based on the literature, the new band structure, including the E_{VB} , E_{CB} , optical bandgap energy, and the substates, were investigated using the ionization energy and the electron affinity energy.^{23,24} Finally, the schematic diagram of the band structure for NaMB/I₂

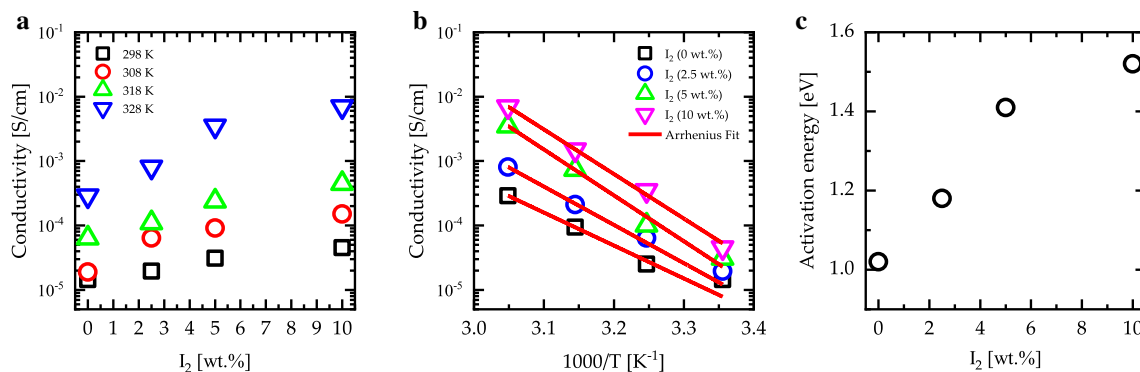


Fig. 7 (a) The electrical conductivity of NaMB/I₂ semiorganic crystal films for different temperatures as a function of I₂ concentrations, (b) electrical conductivity of NaMB/I₂ semiorganic crystal films as

a function of 1000/T [K⁻¹], and (c) activation energy deduced from conductivity fitted to the Arrhenius equation in the temperatures range of 298–328 K.

semiorganic crystal films showed a decrease in the E_{VB} and an increase in the E_{CB} , which enhanced the decreasing trend in E_g as the I₂ concentration increased (Fig. 5f).

Electrical Conductivity

Figure 7a illustrates the electrical conductivity for the NaMB/I₂ semiorganic crystal films for different temperatures as a function of I₂ concentrations. The electrical conductivity of the NaMB/I₂ semiorganic crystal film increased from 0.14 to 0.45 μS/cm by increasing the I₂ concentration to 10 wt.%. The increase in the electrical conductivity values upon increasing I₂ concentration can be attributed to the creation of deep localized states in NaMB, which creates embedded gap states with densities changing by shifting the Fermi level and increasing the electrical conductivity.²⁴ Moreover, increasing the temperature increases the electrical conductivity (Fig. 7a) due to an increase in the cationic thermal activation, which causes a cation to jump to the following coordinating sites and increases the amorphous phase in the semiorganic films.²⁵ Figure 7b shows the variation in electrical conductivity (σ) as a function of temperature [1000/T(K)] for the NaMB/I₂ semiorganic crystal films for different I₂ wt.% fitted via the Arrhenius equation, which means that the samples are thermally activated. Arrhenius-like behavior for σ can be defined as $\sigma = \sigma_0 \exp(-E_a/K_B T)$, where σ_0 is the pre-exponential factor, T is the temperature [K], K_B is the Boltzmann constant, and E_a is the activation energy.²⁶ The activation energy increases by introducing I₂ and enhances the electrical conductivity (Fig. 7c).

Conclusions

The chemical, structural, morphological, optical, and electrical properties of NaMB/I₂ semiorganic crystal films with different weight percents of I₂ were investigated. FTIR spectra and XRD patterns of NaMB/I₂ semiorganic crystal films confirmed the charge transfer between I₂ and NaMB crystals. Based on the XRD measurements, NaMB polymer film has a monoclinic crystal structure with a P21/n space group and a degree of crystallinity of 89.8%. Increasing the I₂ content in the NaMB crystals decreased the crystallinity degree to 74.1% due to disruption of the structure of NaMB. This disruption occurs as a result of the interactions between the NaMB atoms and iodide (I⁻), triiodide (I³⁻), and the molecular iodine (I₂), which reduces the intermolecular interactions in the NaMB crystals. Moreover, introducing I₂ in NaMB crystals decreases the optical bandgap energy due to the formation of polaron states between the valance and conduction bands. The decrease in the bandgap leads to blocking of light in the wavelength range of 250–400 nm; consequently, NaMB/I₂ semiorganic crystal films are potential candidates for use as UV-light-shielding filters. The average electrical conductivity of the NaMB/I₂ semiorganic crystal film increased from 0.14 to 0.45 S/cm with the increase in the I₂ concentration to 10 wt.%. Adding I₂ to the composite led to deep localized states in NaMB, which changed the gap-state densities by shifting the Fermi level and increasing the electrical conductivity.

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Conflict of interest The authors declare that they have no known competing financial interests or personal relationships that could have influenced the work reported in this paper.

Consent to participate All authors participated in this work.

Consent to publish All authors agree to publish this work.

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